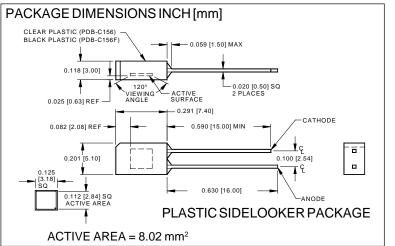
PHOTONIC DETECTORS INC.



Silicon Photodiode, Blue Enhanced Photoconductive Type PDB-C156, with daylight filter Type PDB-C156F



FEATURES

- Large active area
- High speed
- · Low cost
- 25 MHz bandwidth

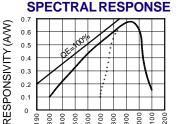
DESCRIPTION: The **PDB-C156** detector is a 8.02 mm² planar pin photodiode housed in a water clear plastic sidelooker package. Designed for high speed, low capacitance, photoconductive applications. The PDB-C156F includes a daylight filter.

APPLICATIONS

- Smoke detectors
- Light dimmers
- TV & VCR remotes
- IR DATA LINKS

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS	
V _{BR}	Reverse Voltage		50	V	
T _{stg}	Storage Temperature	-40	+100	°C	
T _o	Operating Temperature Range	-40	+80	°C	
Τ _s	Soldering Temperature*		+260	°C	
Ι	Light Current		0.5	mA	



WAVELENGTH (nm)

000

0

6 300 100 200 600 7 00 800 006 100 200

*1/16 inch from case for 3 secs max

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TESTCONDITIONS	MIN	TYP	MAX	UNITS
I _{sc}	Short Circuit Current	H = 100 fc, 2850 K	70	90		μ A
I _D	Dark Current	H = 0, V _R = 10 V		2	15	nA
R _{SH}	Shunt Resistance	H = 0, V _R = 10 mV	100	150		MΩ
TCR _{SH}	RSH Temp. Coefficient	H = 0, V _R = 10 mV		-8		% / °C
C	Junction Capacitance	H = 0, V _R = 10 V*		10	15	pF
λrange	Spectral Application Range	(without daylight filter)**	400		1100	nm
λρ	Spectral Response - Peak			950		nm
V _{BR}	Breakdown Voltage	I = 10 μA	30	75		V
NEP	Noise Equivalent Power	V _R = 10 V @ Peak		4.4x10 ⁻¹⁴		W/ √ Hz
tr	Response Time	RL = 1 KΩ V _R = 10 V		15		nS

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. *f = 1 MHz, ** daylight filter= 700 - 1100 nm [FORM NO. 100-PDB-C156 REV A]